

# EVVOSEMI<sup>®</sup>

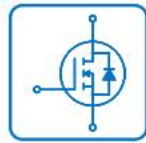
THINK CHANGE DO



ESD



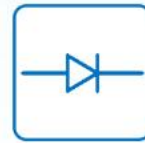
TVS



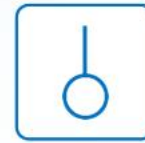
MOS



LDO



Diode



Sensor



DC-DC

## Product Specification

▶ Domestic	Part Number	S1A THRU S1M
▶ Overseas	Part Number	S1A THRU S1M
▶ Equivalent	Part Number	S1A THRU S1M

EV is the abbreviation of name EVVO

## Surface Mount General Purpose Silicon Rectifiers

Reverse Voltage - 50 to 1000 V

Forward Current - 1 A

### FEATURES

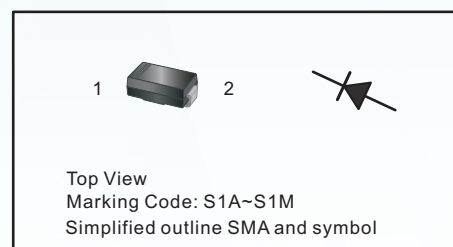
- For surface mounted applications
- Low profile package
- Glass Passivated Chip Junction
- Easy to pick and place
- Lead free in comply with EU RoHS 2011/65/EU directives

### MECHANICAL DATA

- Case: SMA
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.055g / 0.002oz

### PINNING

PIN	DESCRIPTION
1	Cathode
2	Anode



### Maximum Ratings and Electrical characteristics

Ratings at 25 °C ambient temperature unless otherwise specified.

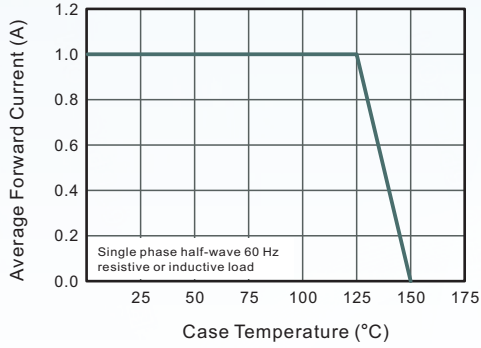
Single phase half-wave 60 Hz, resistive or inductive load, for capacitive load current derate by 20 %.

Parameter	Symbols	S1A	S1B	S1D	S1G	S1J	S1K	S1M	Units
Maximum Repetitive Peak Reverse Voltage	$V_{RRM}$	50	100	200	400	600	800	1000	V
Maximum RMS voltage	$V_{RMS}$	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	$V_{DC}$	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current	$I_{F(AV)}$	1							A
Peak Forward Surge Current 8.3 ms Single Half Sine Wave Superimposed on Rated Load	$I_{FSM}$	30							A
Maximum Instantaneous Forward Voltage at 1 A	$V_F$	1.1							V
Maximum DC Reverse Current at Rated DC Blocking Voltage $T_a = 25\text{ }^\circ\text{C}$ $T_a = 125\text{ }^\circ\text{C}$	$I_R$	5 50							$\mu\text{A}$
Typical Junction Capacitance <sup>(1)</sup>	$C_j$	15							pF
Typical Thermal Resistance <sup>(2)</sup>	$R_{\theta JA}$	75							$^\circ\text{C/W}$
Operating and Storage Temperature Range	$T_j, T_{stg}$	-55 ~ +150							$^\circ\text{C}$

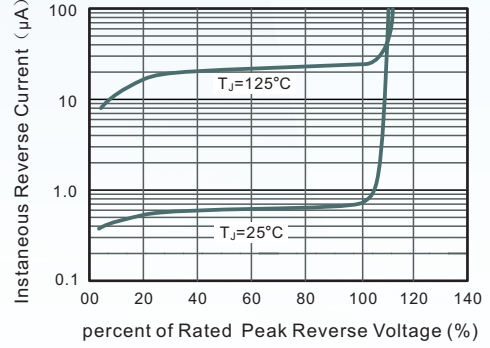
( 1 ) Measured at 1 MHz and applied reverse voltage of 4 V D.C

( 2 ) P.C.B. mounted with 2.0" X 2.0" (5 X 5 cm) copper pad areas.

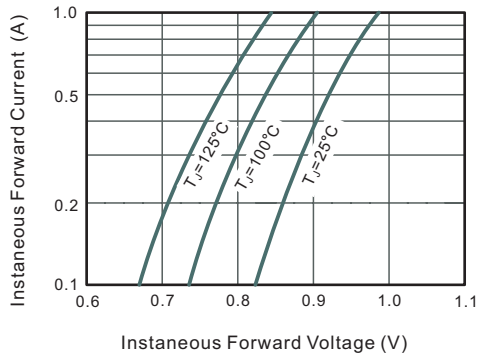
**Fig.1 Forward Current Derating Curve**



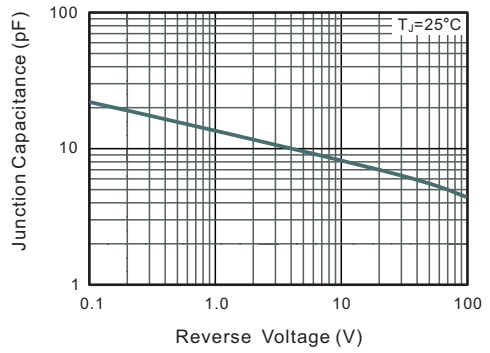
**Fig.2 Typical Reverse Characteristics**



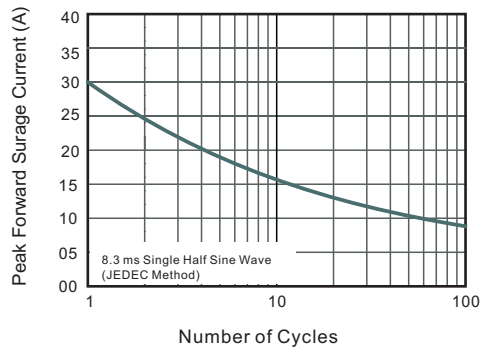
**Fig.3 Typical Forward Characteristic**



**Fig.4 Typical Junction Capacitance**



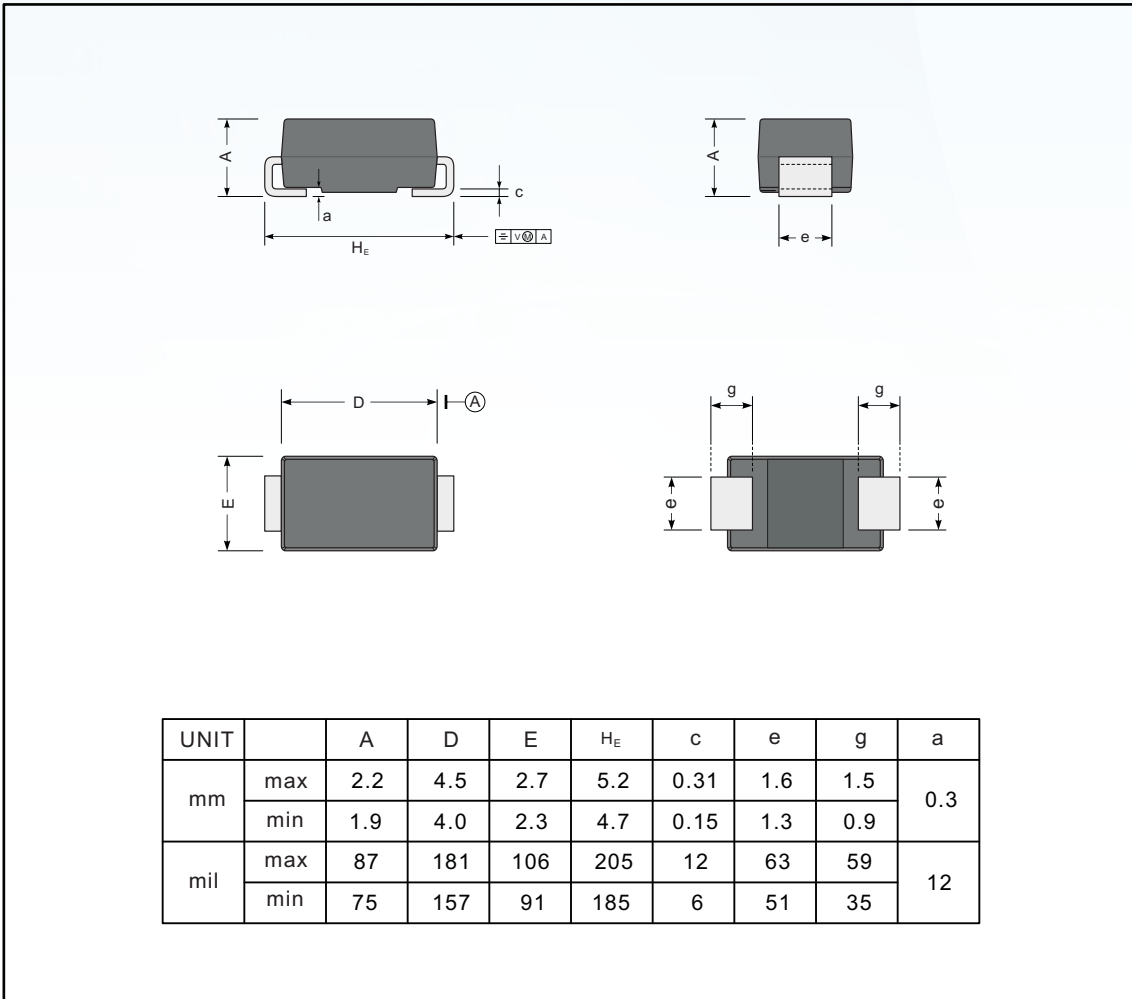
**Fig.5 Maximum Non-Repetitive Peak Forward Surge Current**



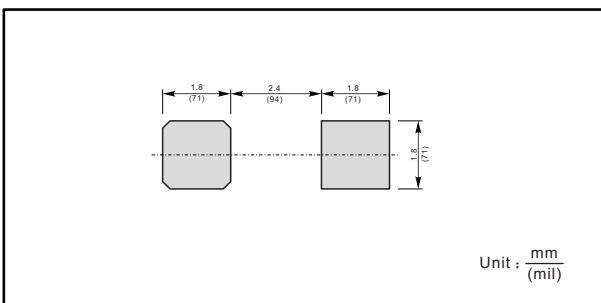
## PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SMA



### The recommended mounting pad size



### Marking

Type number	Marking code
S1A	S1A
S1B	S1B
S1D	S1D
S1G	S1G
S1J	S1J
S1K	S1K
S1M	S1M

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